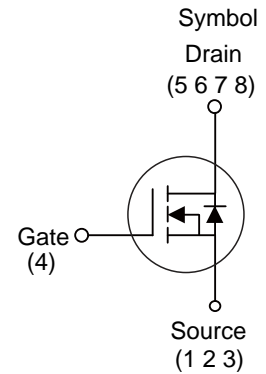


■ PRODUCT CHARACTERISTICS

| | |
|---------------------------------|--------------|
| V_{DSS} | 30V |
| $R_{DS(ON) Typ} (@V_{GS}=10V)$ | 5m Ω |
| $R_{DS(ON) Typ} (@V_{GS}=4.5V)$ | 8 m Ω |
| I_D | 65A |

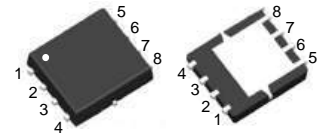


■ APPLICATIONS

- * Electronic lamp ballasts based on half bridge
- * Load Switching, Quick/Wireless Charge.
- * Motor Driving

■ FEATURE

- * Low Gate Charge
- * Pb-Free Lead Plating



PDFN5X6

■ ORDER INFORMATION

| Order Codes | | Package | Packing |
|--------------|----------|---------|------------------|
| Halogen-Free | Halogen | | |
| N/A | MOT3150G | PDFN5X6 | 5000 pieces/Reel |

■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^{\circ}C$, unless otherwise specified)

| Parameter | Symbol | Ratings | Unit |
|--|-----------|-----------|-------------|
| Drain-Source Voltage | V_{DSS} | 30 | V |
| Gate-Source Voltage | V_{GSS} | ± 20 | V |
| Drain Current Continuous ($@V_{GS}=10V, T_A=25^{\circ}C$) | I_D | 65 | A |
| Drain Current Continuous ($@V_{GS}=10V, T_A=100^{\circ}C$) | I_D | 42 | A |
| Drain Current Pulsed | I_{DM} | 260 | A |
| Avalanche Energy * | E_{AS} | 132 | mJ |
| Power Dissipation | P_D | 40 | W |
| Junction Temperature | T_J | +150 | $^{\circ}C$ |
| Storage Temperature | T_{STG} | -55~ +150 | $^{\circ}C$ |

■ THERMAL CHARACTERISTICS

| Parameter | Symbol | Typ | Unit |
|------------------|------------|------|---------------|
| Junction to Case | R_{thJC} | 3.13 | $^{\circ}C/W$ |

Note: * EAS condition: $T_J=25^{\circ}C, V_{DS}=20V, V_G=10V, L=0.5mH, R_g=25\Omega$

■ ELECTRICAL CHARACTERISTICS ($T_C=25^{\circ}\text{C}$, unless otherwise noted)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|---------------------------------------|--------------|--|-----|------|------|------------|
| Off characteristics | | | | | | |
| Drain to Source Breakdown Voltage | V_{DSS} | $V_{GS}=0V, I_D=250\mu A$ | 30 | - | - | V |
| Drain to Source Leakage Current | I_{DSS} | $V_{DS}=30V, V_{GS}=0V$ | - | - | 1 | μA |
| Gate to Source Forward Leakage | $I_{GSS(F)}$ | $V_{GS}=+20V, V_{DS}=0V$ | - | - | 100 | nA |
| Gate to Source Reverse Leakage | $I_{GSS(R)}$ | $V_{GS}=-20V, V_{DS}=0V$ | - | - | -100 | nA |
| On characteristics | | | | | | |
| Drain to Source On-Resistance | $R_{DS(ON)}$ | $V_{GS}=10V, I_D=20A$ | - | 5 | 6 | m Ω |
| | | $V_{GS}=4.5V, I_D=10A$ | - | 8 | 9 | m Ω |
| Gate Threshold Voltage | $V_{GS(TH)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$ | 1 | 1.5 | 2.5 | V |
| Dynamic characteristics | | | | | | |
| Gate capacitance | R_g | $V_{GS}=0V, V_{DS}=0V, f=1.0MHz$ | - | 1.4 | - | Ω |
| Forward Transconductance | g_{fs} | $V_{DS}=5V, I_D=5A$ | - | 14 | - | S |
| Input Capacitance | C_{iss} | $V_{DS}=20V, V_{GS}=0V$ $f=1.0MHz$ | - | 1700 | - | pF |
| Output Capacitance | C_{oss} | | - | 187 | - | pF |
| Reverse Transfer Capacitance | C_{rss} | | - | 154 | - | pF |
| Resistive Switching Characteristics | | | | | | |
| Turn-on Delay Time | $t_{d(ON)}$ | $V_{GS}=10V, V_{DS}=15V,$ $I_D=20A, R_G=1.6\Omega$ | - | 7 | - | ns |
| Rise Time | t_r | | - | 6 | - | ns |
| Turn-off Delay Time | $t_{d(OFF)}$ | | - | 30 | - | ns |
| Fall Time | t_f | | - | 8 | - | ns |
| Total Gate Charge | Q_g | $I_D=20A, V_{DS}=15V$ $V_{GS}=10V$ | - | 30 | - | nC |
| Gate to Source Charge | Q_{gs} | | - | 5.8 | - | nC |
| Gate to Drain("Miller") Charge | Q_{gd} | | - | 7.9 | - | nC |
| Source-Drain Diode Characteristics | | | | | | |
| Continuous Source Current(Body Diode) | I_S | | - | - | 65 | A |
| Maximum Pulsed Current(Body Diode) | I_{SM} | | - | - | 260 | A |
| Diode Forward Voltage | V_{SD} | $I_{SD}=1A, V_{GS}=0V$ | - | 0.73 | 1.2 | V |
| Reverse Recovery Time | t_{rr} | $I_{SD}=20A, T_J=25^{\circ}\text{C}$ $di/dt=100A/\mu s$ | - | 32 | - | ns |
| Reverse Recovery Charge | Q_{rr} | | - | 25 | - | nC |

■ TYPICAL CHARACTERISTICS

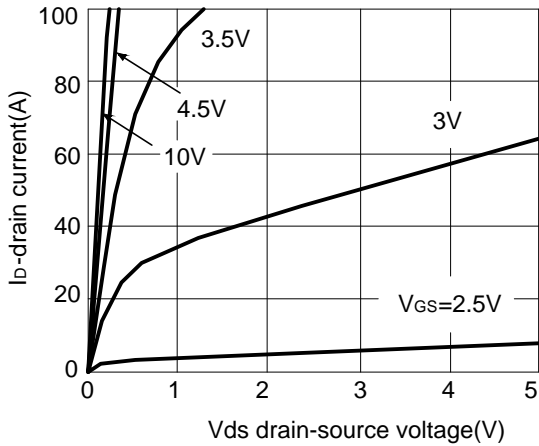


Figure 1: Output characteristics

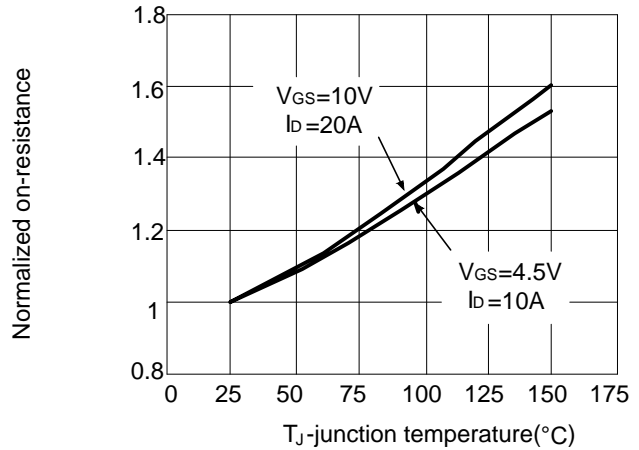


Figure 2: R_{dson} -junction temperature

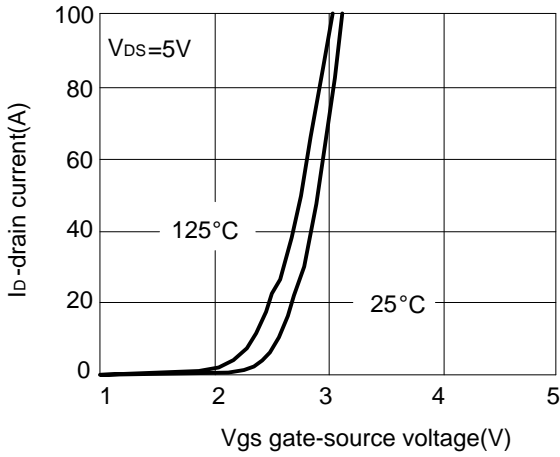


Figure 3: Transfer characteristics

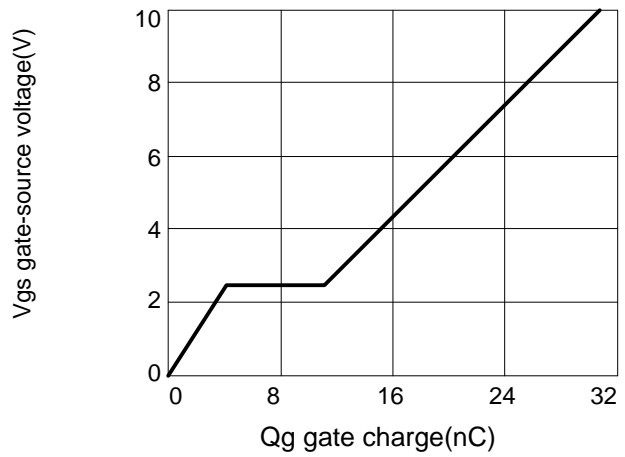


Figure 4: Gate charge

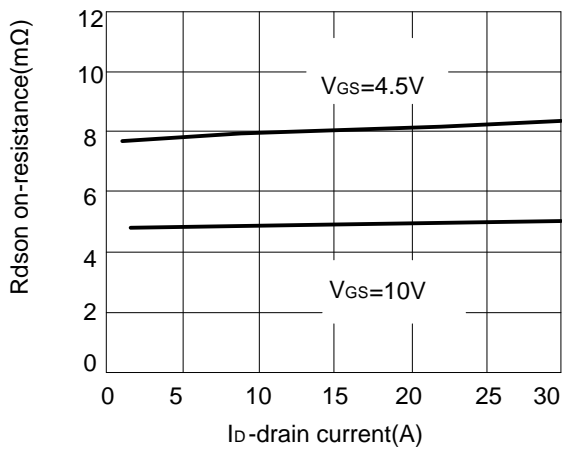


Figure 5: R_{dson} -drain current

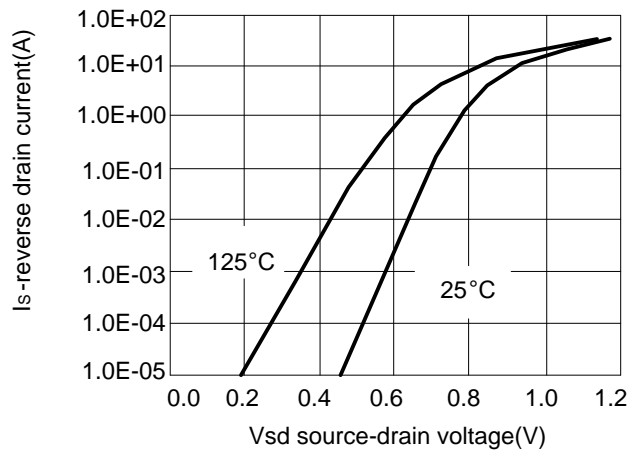


Figure 6: Source-drain diode forward

■ TYPICAL CHARACTERISTICS(Cont.)

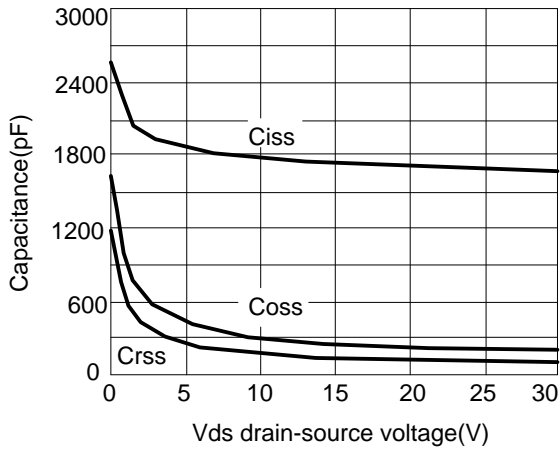


Figure 7: Capacitance vs vds

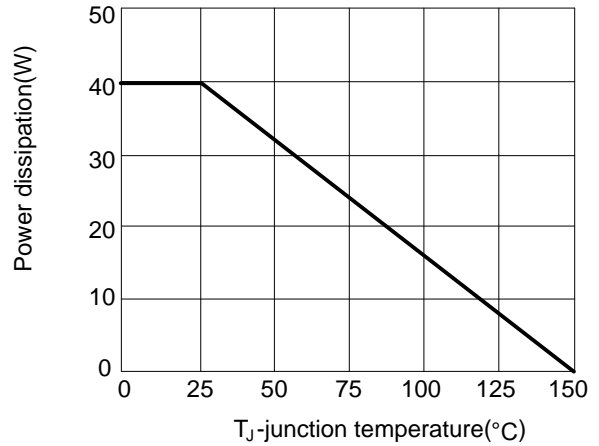


Figure 8: Power de-rating

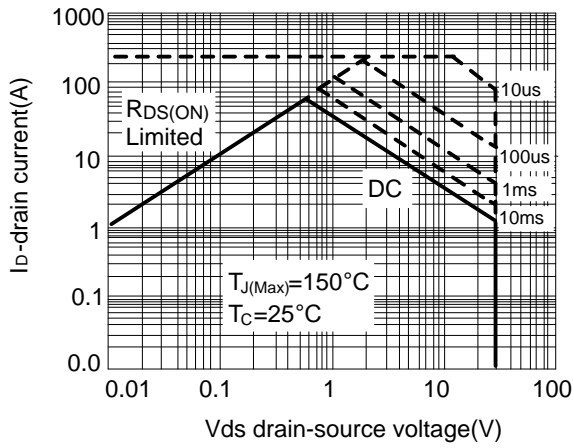


Figure 9: Safe operation area

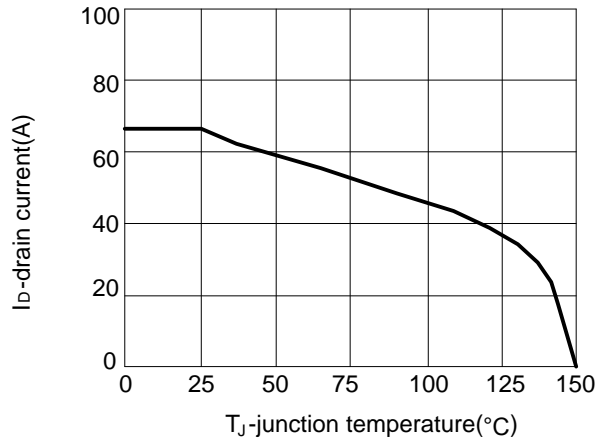
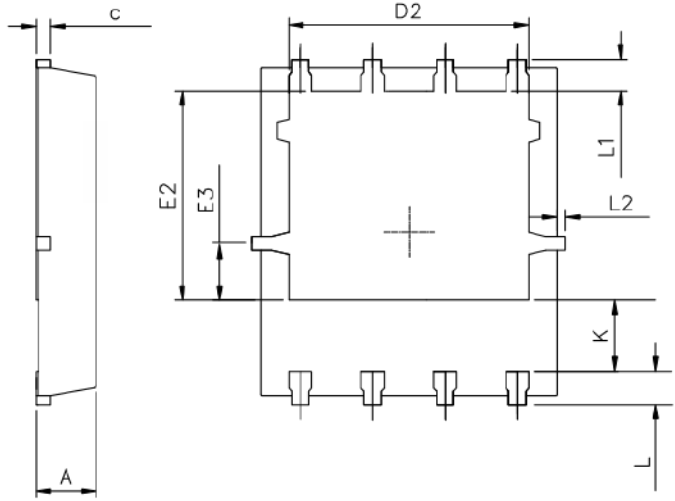
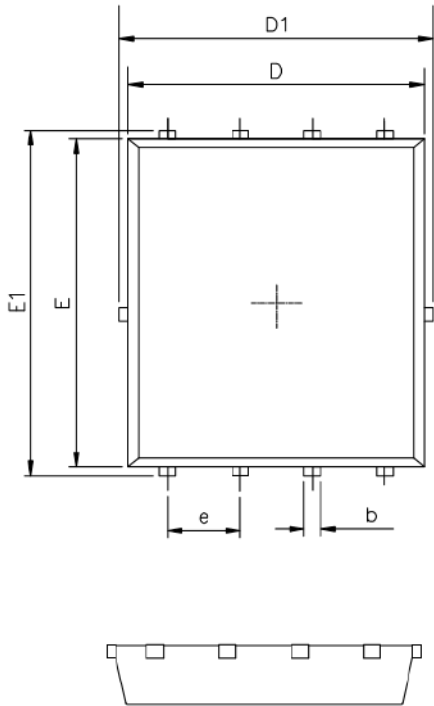
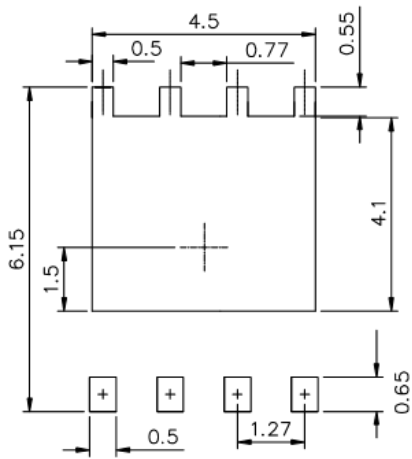


Figure 10: Current de-rating

■ PDFN5X6 PACKAGE OUTLINE DIMENSIONS



RECOMMENDED LAND PATTERN



UNIT:mm

| | MIN | NOM | MAX |
|----|-------|-------|-------|
| A | 0.90 | 1.00 | 1.10 |
| b | 0.25 | 0.35 | 0.50 |
| c | 0.10 | 0.20 | 0.30 |
| D | 4.80 | 5.00 | 5.30 |
| D1 | 4.90 | 5.10 | 5.50 |
| D2 | 3.92 | 4.02 | 4.20 |
| E | 5.65 | 5.75 | 5.85 |
| E1 | 5.90 | 6.05 | 6.20 |
| E2 | 3.325 | 3.525 | 3.775 |
| E3 | 0.80 | 0.90 | 1.00 |
| e | | 1.27 | |
| L | 0.40 | 0.55 | 0.70 |
| L1 | | 0.65 | |
| L2 | 0.00 | | 0.15 |
| K | 1.00 | 1.30 | 1.50 |